

B. Sc. I.T.

2<sup>nd</sup> Semester

Paper : Digital Electronics (BIT - 201)

Time Allowed : 2 ½ Hours

May - 2011

Maximum Marks : 80

Min. Pass Marks : 32

Note :- Attempt all questions from Section A & B and only Two questions from Section C.

~~Section A~~ : Very short answer type questions to be answered in about 20 words (Marks: 2x8=16)

1.
  - i) ✓ Solve in binary  
 $(1-1001)_2 \times (10.101)_2 - (1.0101)_2$
  - ii) ✓ Why are NAND and NOR gates called Universal gates?
  - iii) What is the difference between product term and min-term?
  - iv) ✓ Define a full adder?
  - v) ✓ Draw the circuit of an SR flip flop with NOR gates?
  - vi) ✓ Define Up-down counter?
  - vii) What is meant by distractive read-out?
  - viii) Draw the circuit for a dynamic MOS RAM cell.

Section B : Short answer type questions to be answered in about 250 words (Marks : 4 x 8 = 32)

2. Draw the circuit for a two-input RTL gate and explain its working?
3. Minimize the following Boolean expression using K-map  
 $f(a,b,c,d) = \sum(1,2,3,5,13) + \sum d(6,7,8,9,10,11)$
4. Draw and explain a clocked SR flip flop?
5. Explain how two 16x4 RAMs can be connected to form one 16x8 RAM?

Section C : Long answer type questions to be answered in about 500 words (Marks: 2x 16 = 32)

6.
  - a) Define the terms:
    - i. Fan-in
    - ii. Fan-out
    - iii. Propagation Delay
    - iv. Noise margin
  - b) ✓ Explain the working of a pn junction diode under forward and reverse biasing?
7. ✓
  - a) Explain the working of a multiplexer?
  - b) Realize the following function with a 8:1 multiplexer.
8. Discuss the design of a synchronous decade counter using T-flip flops and show output states and waveforms for each flip flop?
9.
  - a) ✓ Explain linear and coincident selection in a RAM?
  - b) Draw the circuit for a dynamic shift register cell and explain its operation?